

# NSQA6V8AW5T2 Series

## Transient Voltage Suppressor ESD Protection Diode with Low Clamping Voltage

This integrated transient voltage suppressor device (TVS) is designed for applications requiring transient overvoltage protection. It is intended for use in sensitive equipment such as computers, printers, business machines, communication systems, medical equipment, and other applications. Its integrated design provides very effective and reliable protection for four separate lines using only one package. These devices are ideal for situations where board space is at a premium.

### Features

- Low Clamping Voltage
- Small SC-88A SMT Package
- Stand Off Voltage: 5 V
- Low Leakage Current < 1  $\mu$ A
- Four Separate Unidirectional Configurations for Protection
- ESD Protection: IEC61000-4-2: Level 4

MILSTD 883C – Method 3015-6: Class 3

- Pb-Free Packages are Available

### Benefits

- Provides Protection for ESD Industry Standards: IEC 61000, HBM
- Minimize Power Consumption of the System
- Minimize PCB Board Space

### Typical Applications

- Instrumentation Equipment
- Serial and Parallel Ports
- Microprocessor Based Equipment
- Notebooks, Desktops, Servers
- Cellular and Portable Equipment

### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Power Dissipation 8 × 20 $\mu$ sec Double Exponential Waveform (Note 1)	$P_{PK}$	20	W
Steady State Power – 1 Diode (Note 2)	$P_D$	380	mW
Thermal Resistance – Junction-to-Ambient Above 25°C, Derate	$R_{\theta JA}$	327 3.05	$^\circ\text{C/W}$ mW/ $^\circ\text{C}$
Operating Junction Temperature Range	$T_J$	-40 to +125	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-55 to +150	$^\circ\text{C}$
Lead Solder Temperature – Maximum 10 Seconds Duration	$T_L$	260	$^\circ\text{C}$
IEC 61000-4-2 (ESD) Contact		$\pm 8.0$	kV

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

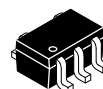
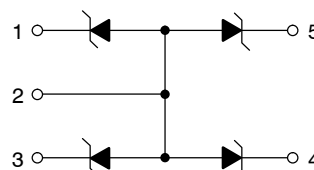
1. Non-repetitive current pulse per Figure 6.
2. Only 1 diode under power. For all 4 diodes under power,  $P_D$  will be 25%. Mounted on FR4 board with min pad.

See Application Note AND8308/D for further description of survivability specs.



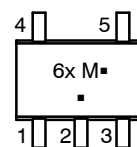
**ON Semiconductor®**

<http://onsemi.com>



SC-88A/SOT-323  
CASE 419A

### MARKING DIAGRAM



- x = H for NSQA6V8AW5T2  
X for NSQA12VAW5T2
- M = Date Code
- = Pb-Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NSQA6V8AW5T2	SC-88A	3000/Tape & Reel
NSQA6V8AW5T2G	SC-88A (Pb-Free)	3000/Tape & Reel
NSQA12VAW5T2	SC-88A	3000/Tape & Reel
NSQA12VAW5T2G	SC-88A (Pb-Free)	3000/Tape & Reel

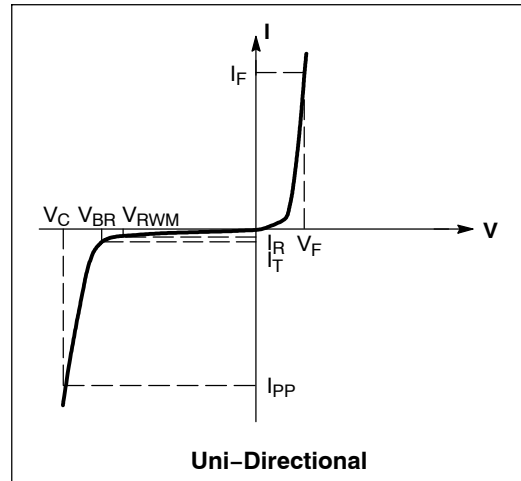
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## NSQA6V8AW5T2 Series

### ELECTRICAL CHARACTERISTICS

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Symbol	Parameter
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Working Peak Reverse Voltage
$I_R$	Maximum Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$I_F$	Forward Current
$V_F$	Forward Voltage @ $I_F$
$P_{pk}$	Peak Power Dissipation
$C$	Capacitance @ $V_R = 0$ and $f = 1.0$ MHz



\*See Application Note AND8308/D for detailed explanations of datasheet parameters.

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

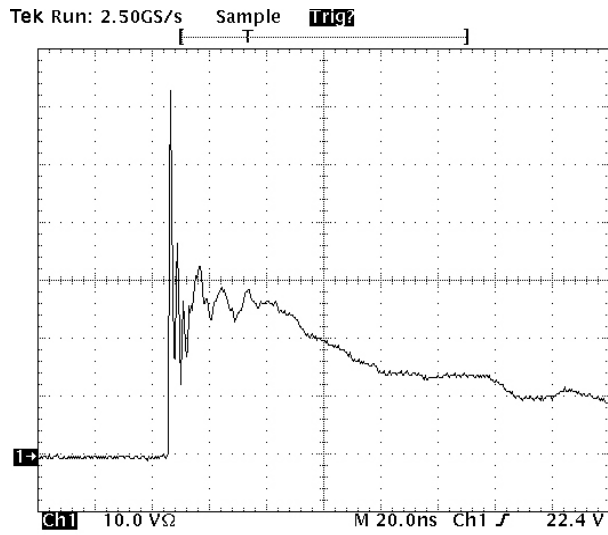
Characteristic	Symbol	Min	Typ	Max	Unit
<b>NSQA6V8AW5T2</b>					
Breakdown Voltage ( $I_T = 1$ mA) (Note 3)	$V_{BR}$	6.4	6.8	7.1	V
Leakage Current ( $V_{RWM} = 5.0$ V)	$I_R$	-	-	1.0	$\mu\text{A}$
Clamping Voltage 1 ( $I_{PP} = 1.6$ A) (Note 4)	$V_C$	-	-	13	V
Maximum Peak Pulse Current (Note 4)	$I_{PP}$	-	-	1.6	A
Junction Capacitance - ( $V_R = 0$ V, $f = 1$ MHz) - ( $V_R = 3.0$ V, $f = 1$ MHz)	$C_J$	-	12 6.7	15 9.5	pF
Clamping Voltage - Per IEC61000-4-2	$V_C$	Figures 1 and 2			V
<b>NSQA12VAW5T2</b>					
Breakdown Voltage ( $I_T = 5$ mA) (Note 3)	$V_{BR}$	11.4	12.0	12.7	V
Leakage Current ( $V_{RWM} = 9.0$ V)	$I_R$	-	-	0.05	$\mu\text{A}$
Zener Impedance ( $I_T = 5$ mA)	$Z_Z$	-	-	30	$\Omega$
Clamping Voltage 1 ( $I_{PP} = 0.9$ A) (Note 4)	$V_C$	-	-	23	V
Maximum Peak Pulse Current (Note 4)	$I_{PP}$	-	-	0.9	A
Junction Capacitance - ( $V_R = 0$ V, $f = 1$ MHz)	$C_J$	-	-	15	pF
Clamping Voltage - Per IEC61000-4-2 (Note 5)	$V_C$	Figures 1 and 2			V

3.  $V_{BR}$  is measured at pulse test current  $I_T$ .

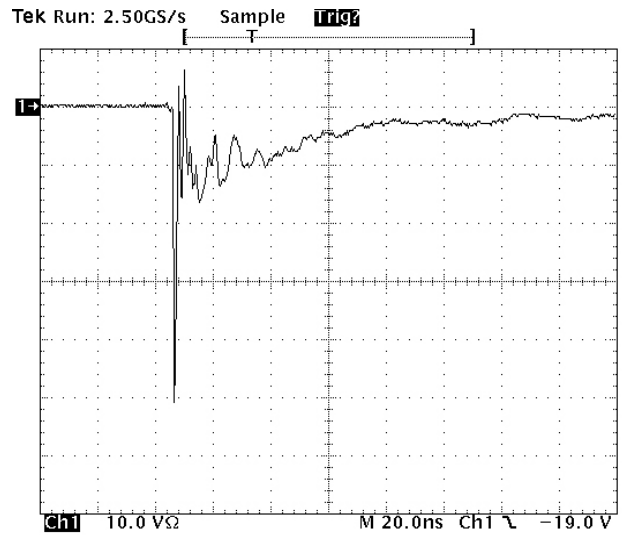
4. Surge current waveform per Figure 5.

5. For test procedure see Figures 3 and 4 and Application Note AND8307/D.

# NSQA6V8AW5T2 Series



**Figure 1. ESD Clamping Voltage Screenshot  
Positive 8 kV Contact per IEC61000-4-2**



**Figure 2. ESD Clamping Voltage Screenshot  
Negative 8 kV Contact per IEC61000-4-2**

# NSQA6V8AW5T2 Series

## IEC 61000-4-2 Spec.

Level	Test Voltage (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

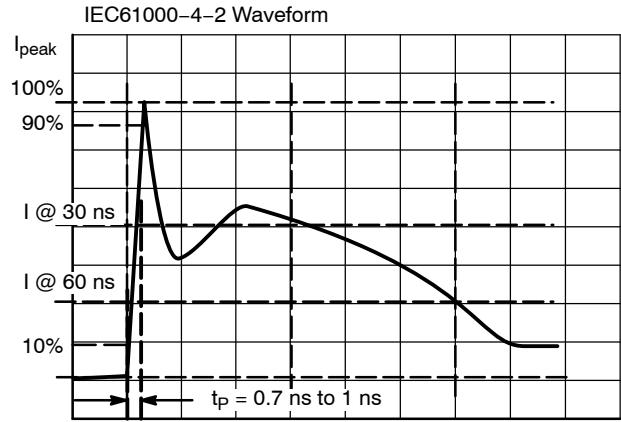


Figure 3. IEC61000-4-2 Spec

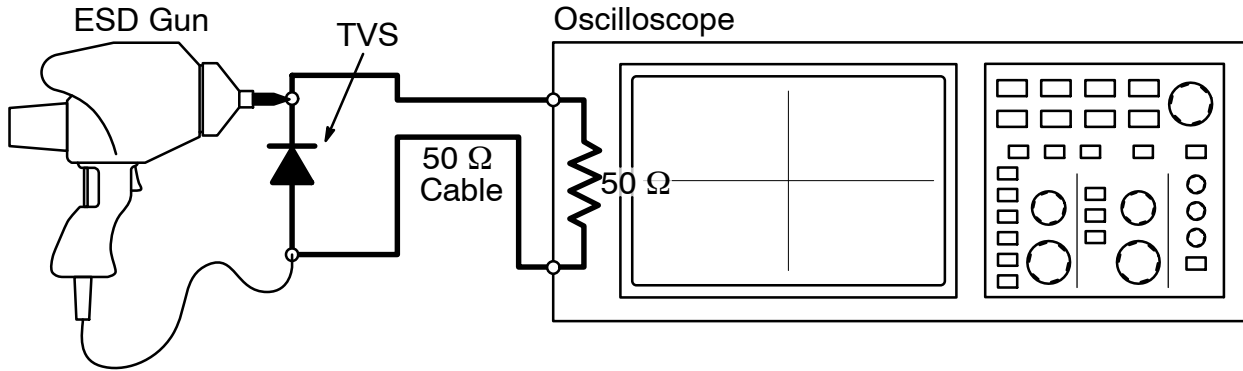


Figure 4. Diagram of ESD Test Setup

The following is taken from Application Note AND8308/D – Interpretation of Datasheet Parameters for ESD Devices.

### ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger

systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level. ON Semiconductor has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how ON Semiconductor creates these screenshots and how to interpret them please refer to AND8307/D.

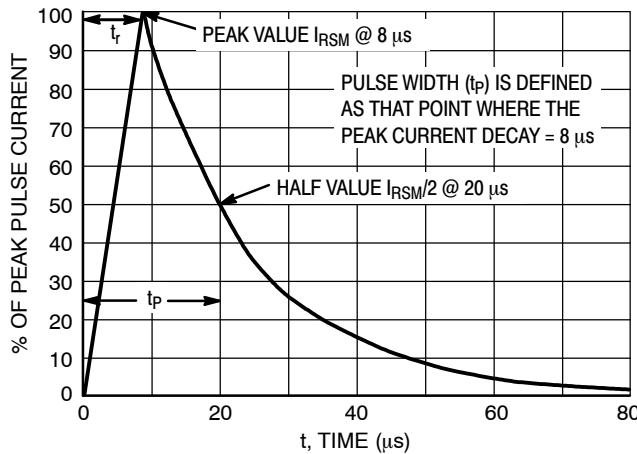


Figure 5. 8 X 20 μs Pulse Waveform

# NSQA6V8AW5T2 Series

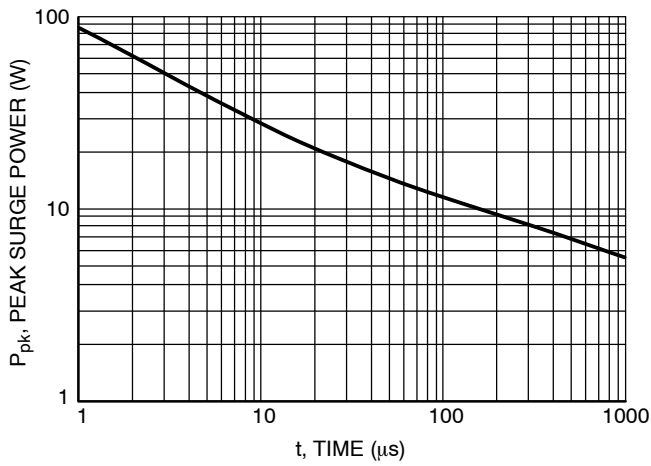


Figure 6. Pulse Width

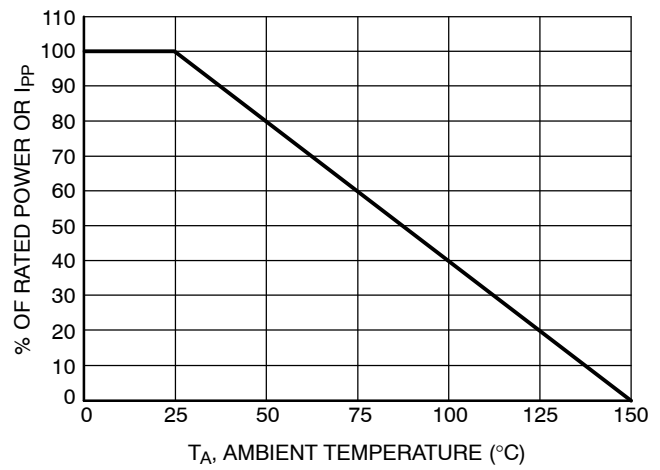


Figure 7. Power Derating Curve

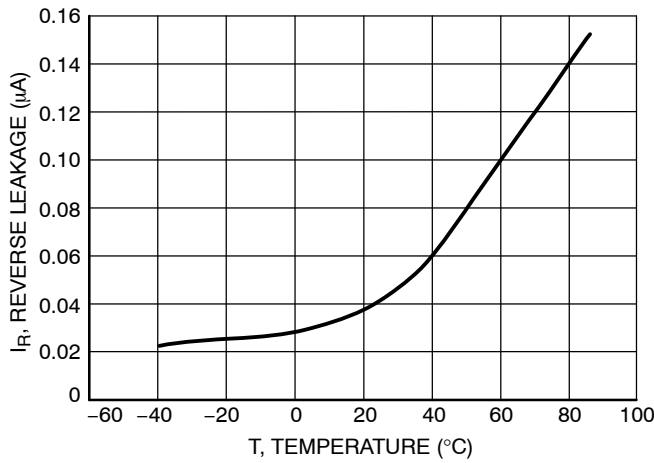


Figure 8. Reverse Leakage versus Temperature

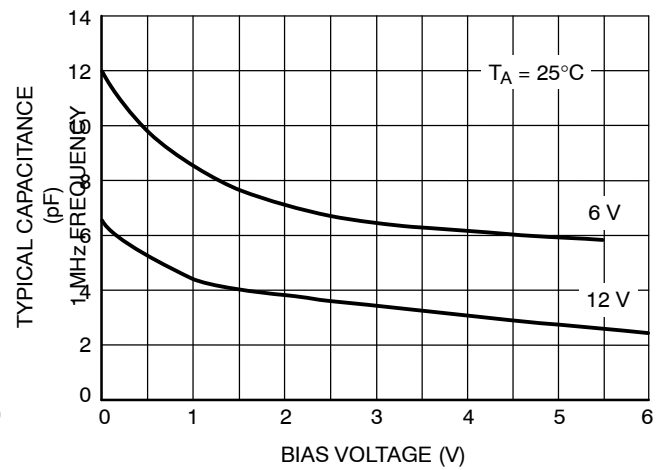


Figure 9. Capacitance

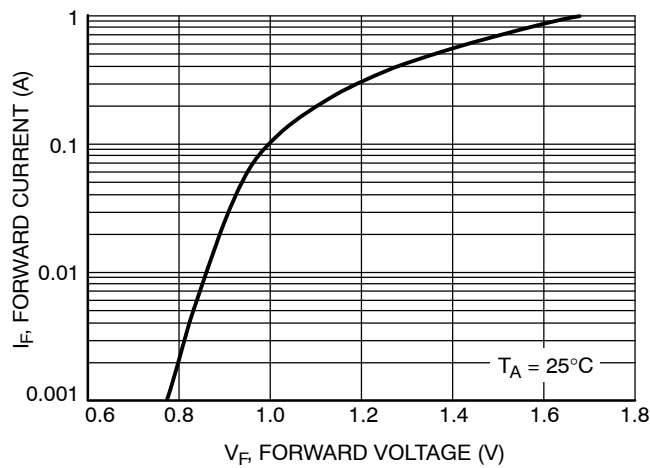
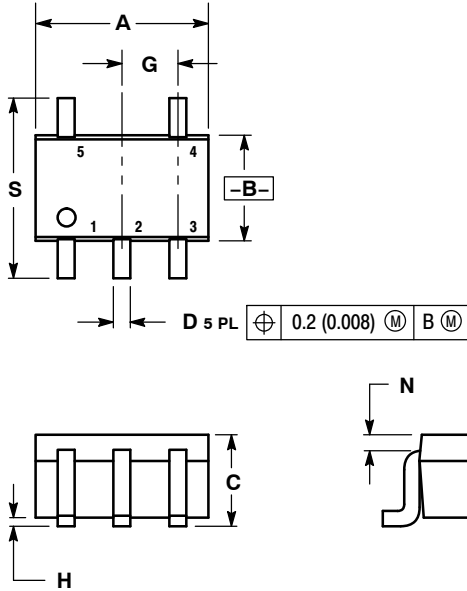


Figure 10. Forward Voltage

# NSQA6V8AW5T2 Series

## PACKAGE DIMENSIONS

SC-88A/SOT-323/SC-70  
5-LEAD PACKAGE  
CASE 419A-02  
ISSUE J

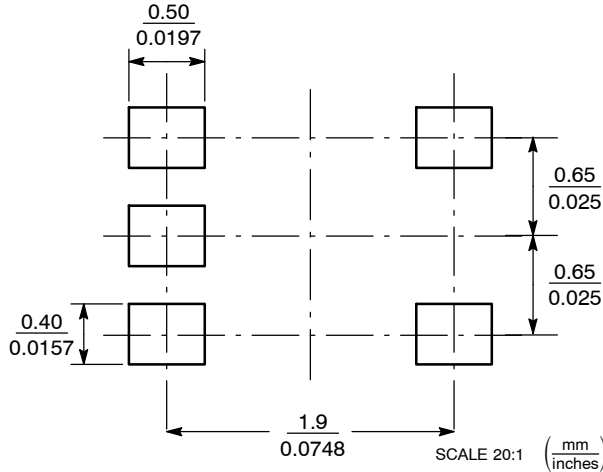


### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
H	---	0.004	---	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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